

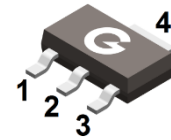
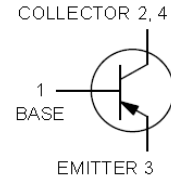
Features

- Epitaxial planar die construction
- Complementary NPN type available(PZT5551)
- RoHS compliant with Halogen-free

HF

Mechanical Data

- Case: SOT-223
- Molding compound: UL flammability classification rating 94V-0
- Terminals: Tin-plated; solderability per MIL-STD-202, Method 208



SOT-223

Ordering Information

Part Number	Package	Shipping Quantity	Marking Code
PZT5401	SOT-223	4000 pcs / Tape & Reel	2L

Maximum Ratings (@ T_A = 25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-160	V
Collector-Emitter Breakdown Voltage	V _{CEO}	-150	V
Emitter-Base Breakdown Voltage	V _{EBO}	-5	V
Continuous Collector Current	I _C	-0.6	A
Peak Collector Current (t _p ≤ 1ms)	I _{CM}	-0.8	A

Thermal Characteristics

Parameter	Symbol	Value	Unit
Power Dissipation (Collector) *1	P _D	1.15	W
Thermal Resistance (Junction-to-Ambient)	R _{θJA}	108	°C/W
Junction Temperature	T _J	-55 ~ +150	°C
Storage Temperature Range	T _{STG}	-55 ~ +150	°C

Note1: Device mounted on a printed-circuit board, single-sided copper, tinplated, mounting pad for collector 1 cm²

Electrical Characteristics (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = -100\mu\text{A}, I_E = 0$	-160	-	-	V
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = -1\text{mA}, I_B = 0$	-150	-	-	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = -10\mu\text{A}, I_C = 0$	-5	-	-	V
Collector Cut-off Current	I_{CBO}	$V_{CB} = -120\text{V}, I_E = 0$	-	-	-50	nA
Emitter Cut-off Current	I_{EBO}	$V_{EB} = -3\text{V}, I_C = 0$	-	-	-50	nA
DC Current Gain	h_{FE}	$V_{CE} = -5\text{V}, I_C = -1\text{mA}$	50	-	-	-
		$V_{CE} = -5\text{V}, I_C = -10\text{mA}$	100	-	300	-
		$V_{CE} = -5\text{V}, I_C = -50\text{mA}$	50	-	-	-
Collector-emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = -10\text{mA}, I_B = -1\text{mA}$	-	-	-0.2	V
		$I_C = -50\text{mA}, I_B = -5\text{mA}$	-	-	-0.5	V
Base-emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = -10\text{mA}, I_B = -1\text{mA}$	-	-	-1	V
		$I_C = -50\text{mA}, I_B = -5\text{mA}$	-	-	-1	V
Collector-base Output Capacitance	C_{cbo}	$V_{CB} = -10\text{V}, f = 1\text{MHz}, I_E = 0$	-	-	6	pF
Current-Gain— Bandwidth Product	f_T	$I_C = -10\text{mA}, V_{CE} = -10\text{V}$ $f = 100\text{MHz}$	100	-	300	MHz

Ratings and Characteristics Curves (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

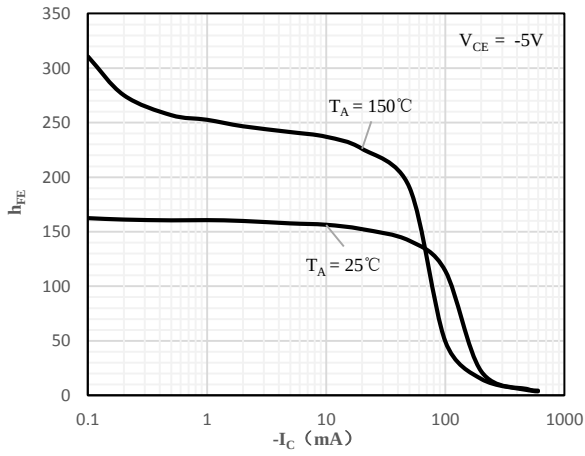


Fig 1 h_{FE} vs. I_C

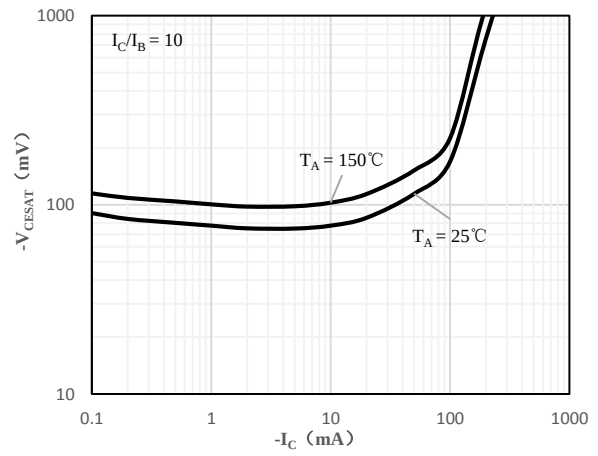


Fig 2 $V_{CE(sat)}$ vs. I_C

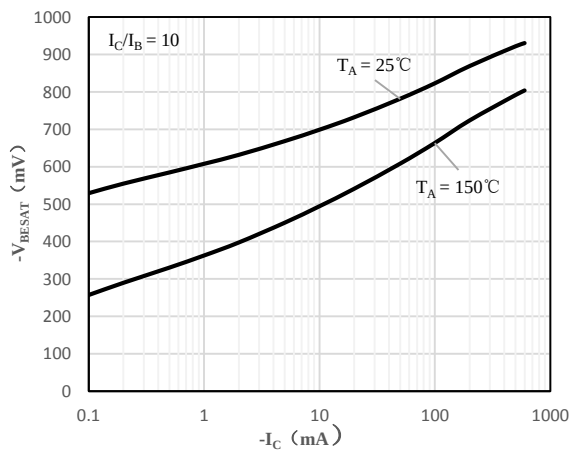


Fig 3 $V_{BE(sat)}$ vs. I_C

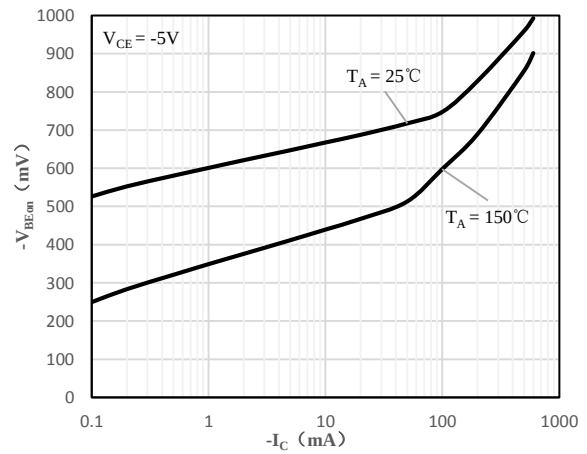
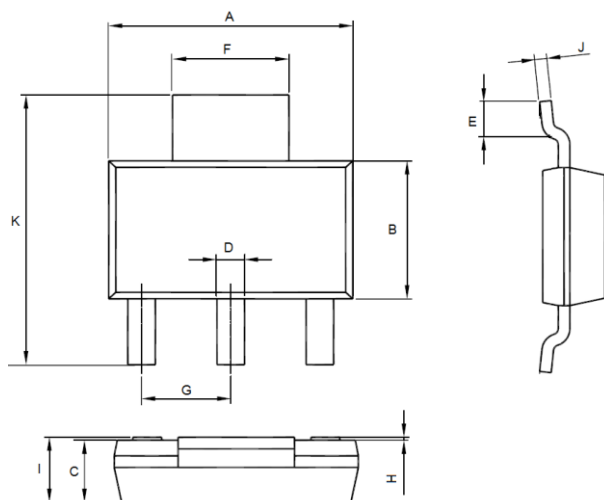


Fig 4 $V_{BE(on)}$ vs. I_C

Package Outline Dimensions (Unit: mm)



SOT-223		
Dimension	Min.	Max.
A	6.10	6.50
B	3.30	3.70
C	1.50	1.70
D	0.66	0.82
E	0.90	1.15
F	2.90	3.10
G	2.20	2.40
H	0.02	0.10
I	1.52	1.80
J	0.20	0.40
K	6.70	7.30

Mounting Pad Layout (Unit: mm)

SOT-223

